Features:	Compact moistur	e resistant	p ackage				
Lowest "on" resistance							
Low distortion							
Ideal for Hi-Fi stereo applications							
Storage Te	mperature :	-30 to+80 C					
Operating	Temperature:	-30 to+80°C					
Soldering	Temperature:	260 °C <10s					
Isolation V	oltage(peak):	2000V					

- > Linear Output Type Light Sensor
- RoHS Compliant / Pb-free / Cd-free



Symbol	Parameter	Min	Тур	Max	Units	TestConditions
LED						
IF	Forward Current			40	mA	(Derate Linearly to 0 at 75° C)
VF	Forward Voltage			2.5	V	IF = 16 mA
Ir	Reverse Current			100	μΑ	VR=3.8V
Cell						
Vc	Maximum Cell Voltage			60	V	(Peak AC or DC)
PD	Power Dissipation			50	mW	(Derate Linearly to 0 at 75° C)
Coupled						
Ron	On Resistance	4. 0		7.0	KΩ	IF = 0.5mA**
Roff	Off Resistance	10.0			MΩ	10sec after I=0.3Vdc on cell
Tr	Rise Time			2.5	msec	Time to 63% of final conductance @ IF = 16 mA ***
TF	Decay Time			35	msec	Time to $100K\Omega$ after removal of input @ IF = 16 mA
	Cell Temp Coefficient		1.0		%°C	IF >5 mA

* 2mm from case for < 5 sec

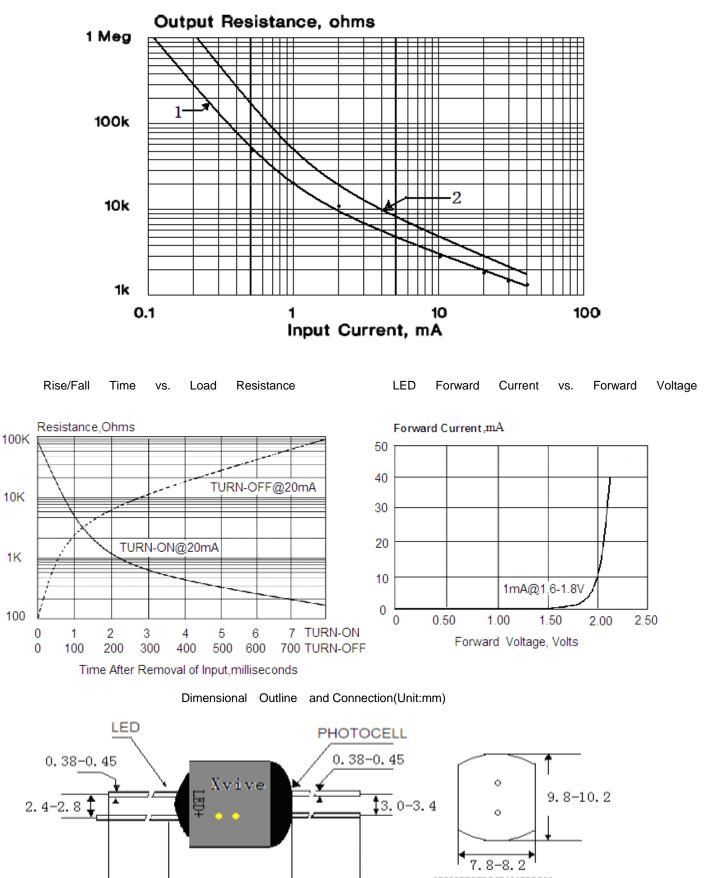
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- measured after a dark history of 1 week
- Rise time is the time for the dark change in conductance to reach 63% of its final value

Output Resistance vs. Forward Current

1K



25 Min

LED

PHOTOCELL

21Min

15Max